

## LONG CREEPAGE TYPE HIGH ISOLATION VOLTAGE 4-PIN PHOTOCOUPLER

–NEPOC Series–

### DESCRIPTION

The PS2581L1, PS2581L2 are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor in a plastic DIP (Dual In-line Package).

Creepage distance and clearance of leads are over 8 millimeters.

The PS2581L2 is lead bending type (Gull-wing) for surface mounting.

### FEATURES

- Long creepage and clearance distance (8 mm)
- High isolation voltage (BV = 5 000 Vr.m.s.)
- High collector to emitter voltage ( $V_{CEO} = 80 \text{ V}$ )
- High-speed switching ( $t_r = 3 \mu\text{s}$  TYP.,  $t_f = 5 \mu\text{s}$  TYP.)
- High current transfer ratio (CTR = 200 % TYP.)
- UL approved: File No. E72422 (S)
- CSA approved: No. CA101391
- BSI approved: No. 8243/8244
- NEMKO approved: No. P97103006
- DEMKO approved: No. 307269
- SEMKO approved: No. 9741154/01
- FIMKO approved: No. 018277
- VDE0884 approved

### ORDERING INFORMATION (Solder Contains Lead)

| Part Number     | Package                                   | Safety Standard Approval    | Application Part Number <sup>*1</sup> |
|-----------------|-------------------------------------------|-----------------------------|---------------------------------------|
| PS2581L1        | 4-pin DIP                                 | UL, CSA, BSI, NEMKO, DEMKO, | PS2581L1                              |
| PS2581L2        | 4-pin DIP<br>(lead bending surface mount) | SEMKO, FIMKO, VDE approved  | PS2581L2                              |
| PS2581L2-E3, E4 | 4-pin DIP taping                          |                             |                                       |

\*1 As applying to Safety Standard, following part number should be used.

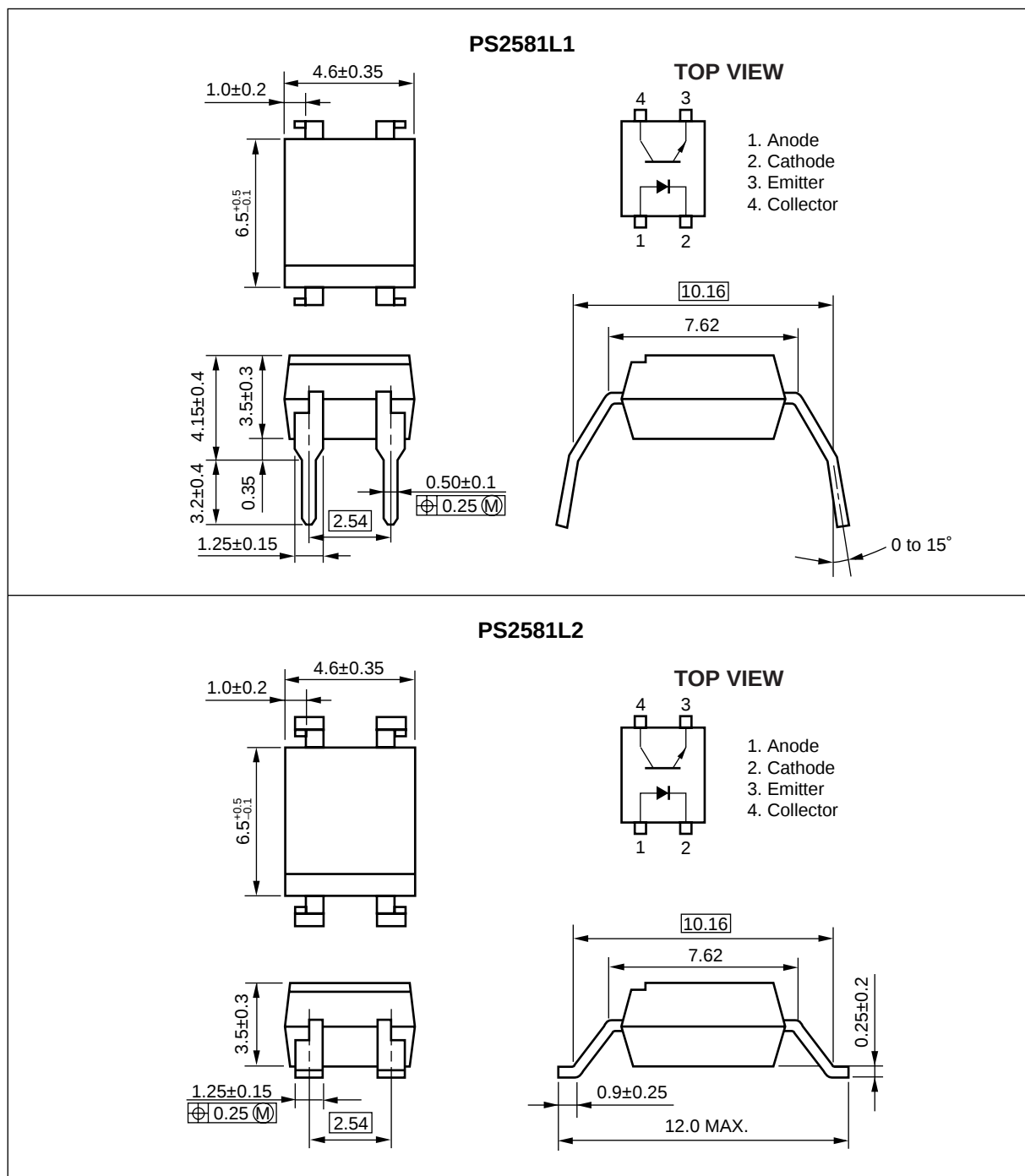
### ORDERING INFORMATION (Pb-Free)

| Part Number       | Package                                   | Safety Standard Approval    | Application Part Number <sup>*1</sup> |
|-------------------|-------------------------------------------|-----------------------------|---------------------------------------|
| PS2581L1-A        | 4-pin DIP                                 | UL, CSA, BSI, NEMKO, DEMKO, | PS2581L1                              |
| PS2581L2-A        | 4-pin DIP<br>(lead bending surface mount) | SEMKO, FIMKO, VDE approved  | PS2581L2                              |
| PS2581L2-E3, E4-A | 4-pin DIP taping                          |                             |                                       |

\*1 As applying to Safety Standard, following part number should be used.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

## PACKAGE DIMENSIONS (in millimeters)



## PHOTOCOUPLER CONSTRUCTION

| Parameter               | Unit (MIN.) |
|-------------------------|-------------|
| Air Distance            | 8 mm        |
| Outer Creepage Distance | 8 mm        |
| Inner Creepage Distance | 4 mm        |
| Isolation Distance      | 0.4 mm      |

**ABSOLUTE MAXIMUM RATINGS ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)**

| Parameter                       |                                    | Symbol                        | Ratings     | Unit                   |
|---------------------------------|------------------------------------|-------------------------------|-------------|------------------------|
| Diode                           | Forward Current (DC)               | $I_F$                         | 80          | mA                     |
|                                 | Reverse Voltage                    | $V_R$                         | 6           | V                      |
|                                 | Power Dissipation Derating         | $\Delta P_D/^{\circ}\text{C}$ | 1.5         | mW/ $^{\circ}\text{C}$ |
|                                 | Power Dissipation                  | $P_D$                         | 150         | mW                     |
|                                 | Peak Forward Current <sup>*1</sup> | $I_{FP}$                      | 1           | A                      |
| Transistor                      | Collector to Emitter Voltage       | $V_{CEO}$                     | 80          | V                      |
|                                 | Emitter to Collector Voltage       | $V_{ECO}$                     | 7           | V                      |
|                                 | Collector Current                  | $I_C$                         | 50          | mA                     |
|                                 | Power Dissipation Derating         | $\Delta P_C/^{\circ}\text{C}$ | 1.5         | mW/ $^{\circ}\text{C}$ |
|                                 | Power Dissipation                  | $P_C$                         | 150         | mW                     |
| Isolation Voltage <sup>*2</sup> |                                    | BV                            | 5 000       | Vr.m.s.                |
| Operating Ambient Temperature   |                                    | $T_A$                         | -55 to +100 | $^{\circ}\text{C}$     |
| Storage Temperature             |                                    | $T_{stg}$                     | -55 to +150 | $^{\circ}\text{C}$     |

<sup>\*1</sup> PW = 100  $\mu\text{s}$ , Duty Cycle = 1 %

<sup>\*2</sup> AC voltage for 1 minute at  $T_A = 25\text{ }^{\circ}\text{C}$ , RH = 60 % between input and output

ELECTRICAL CHARACTERISTICS ( $T_A = 25\text{ }^{\circ}\text{C}$ )

| Parameter  |                                                    | Symbol        | Conditions                                                              | MIN.      | TYP. | MAX. | Unit          |
|------------|----------------------------------------------------|---------------|-------------------------------------------------------------------------|-----------|------|------|---------------|
| Diode      | Forward Voltage                                    | $V_F$         | $I_F = 10\text{ mA}$                                                    |           | 1.17 | 1.4  | V             |
|            | Reverse Current                                    | $I_R$         | $V_R = 5\text{ V}$                                                      |           |      | 5    | $\mu\text{A}$ |
|            | Terminal Capacitance                               | $C_t$         | $V = 0\text{ V}, f = 1.0\text{ MHz}$                                    |           | 50   |      | pF            |
| Transistor | Collector to Emitter Dark Current                  | $I_{CEO}$     | $V_{CE} = 80\text{ V}, I_F = 0\text{ mA}$                               |           |      | 100  | nA            |
| Coupled    | Current Transfer Ratio ( $I_C/I_F$ ) <sup>*1</sup> | CTR           | $I_F = 5\text{ mA}, V_{CE} = 5\text{ V}$                                | 80        | 200  | 400  | %             |
|            | Collector Saturation Voltage                       | $V_{CE(sat)}$ | $I_F = 10\text{ mA}, I_C = 2\text{ mA}$                                 |           |      | 0.3  | V             |
|            | Isolation Resistance                               | $R_{I-O}$     | $V_{I-O} = 1.0\text{ kV}_{DC}$                                          | $10^{11}$ |      |      | $\Omega$      |
|            | Isolation Capacitance                              | $C_{I-O}$     | $V = 0\text{ V}, f = 1.0\text{ MHz}$                                    |           | 0.5  |      | pF            |
|            | Rise Time <sup>*2</sup>                            | $t_r$         | $V_{CC} = 10\text{ V}, I_C = 2\text{ mA},$<br>$R_L = 100\text{ }\Omega$ |           | 3    |      | $\mu\text{s}$ |
|            | Fall Time <sup>*2</sup>                            | $t_f$         |                                                                         |           | 5    |      |               |

**\*1** CTR rank

L : 200 to 400 (%)

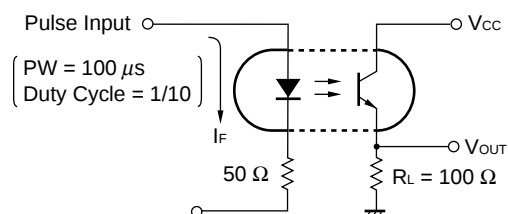
M : 80 to 240 (%)

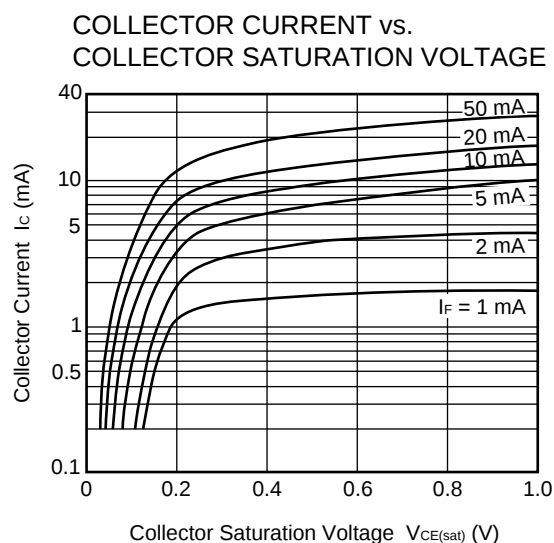
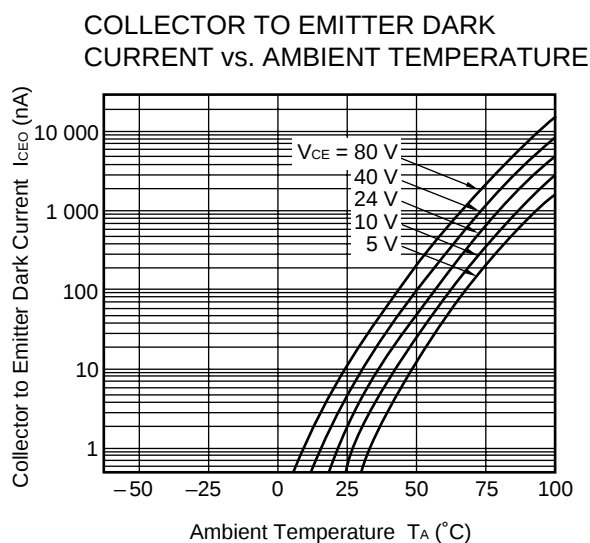
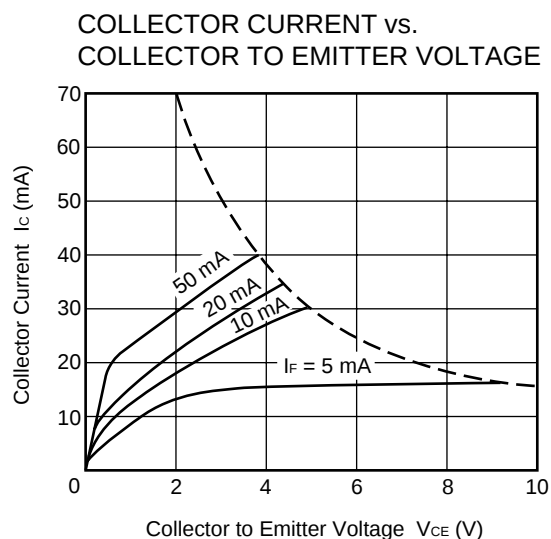
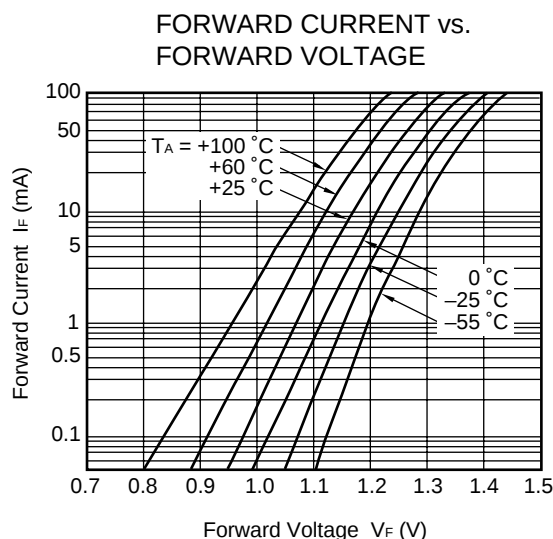
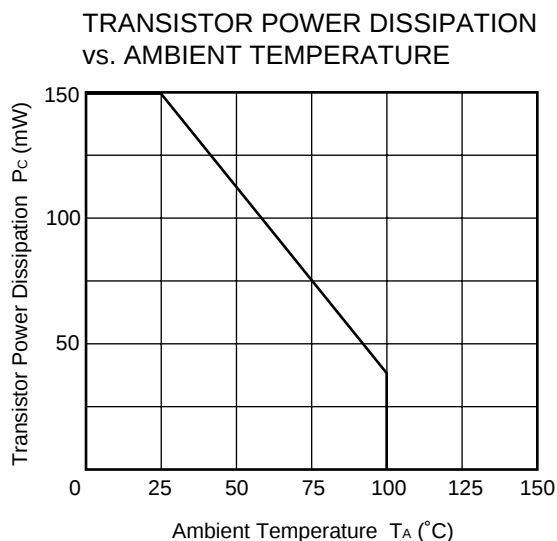
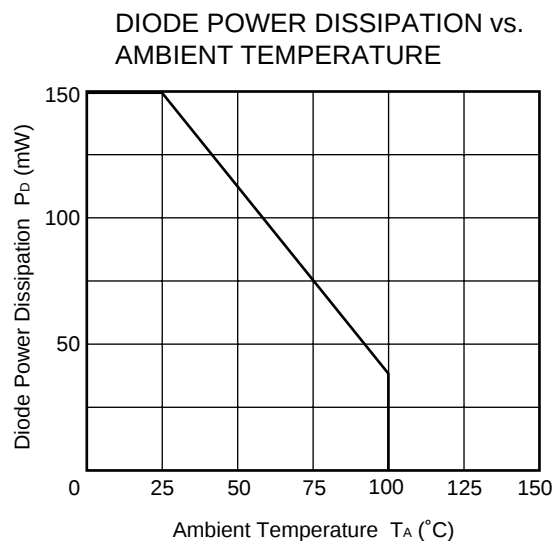
D : 100 to 300 (%)

H : 80 to 160 (%)

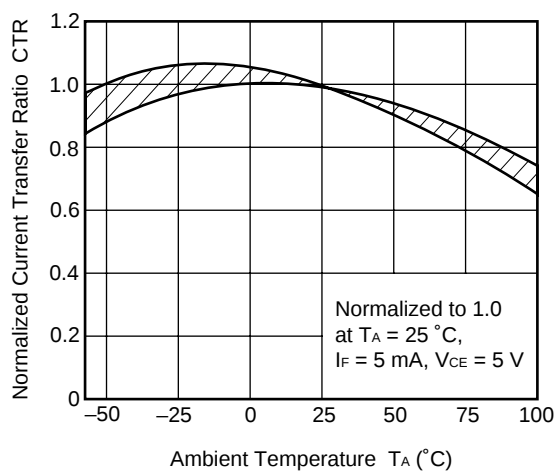
W : 130 to 260 (%)

N : 80 to 400 (%)

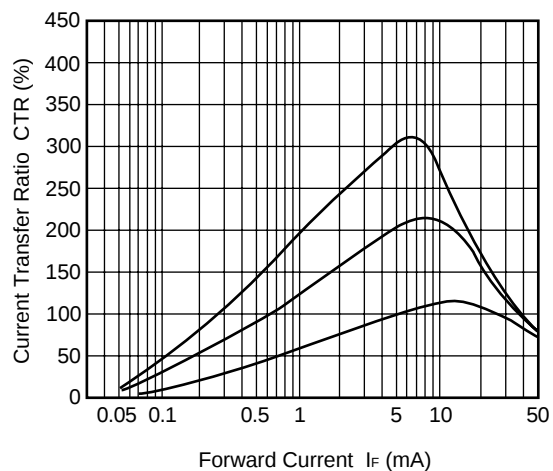
**\*2** Test circuit for switching time

TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ , unless otherwise specified)

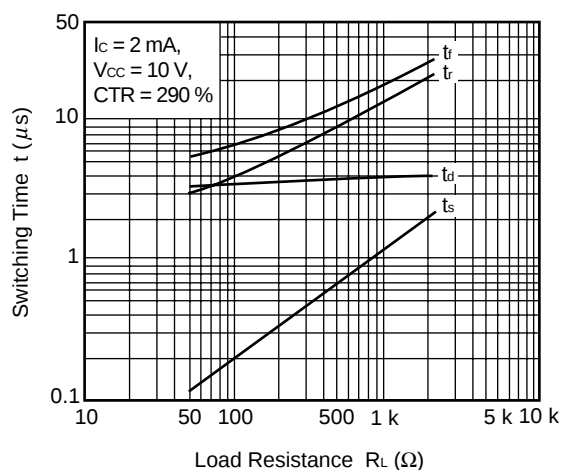
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



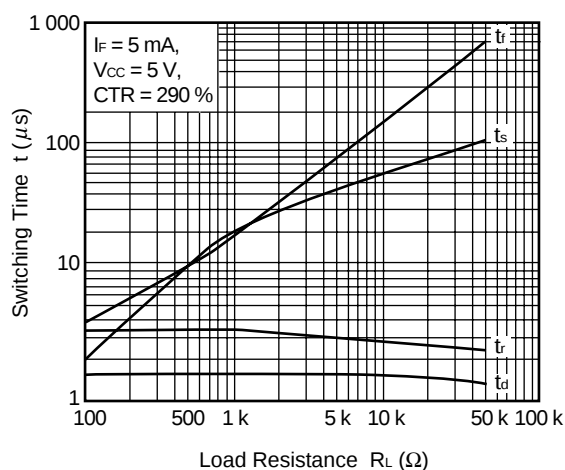
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



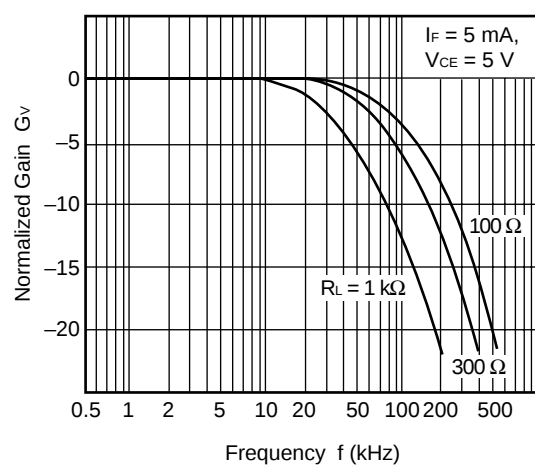
SWITCHING TIME vs. LOAD RESISTANCE



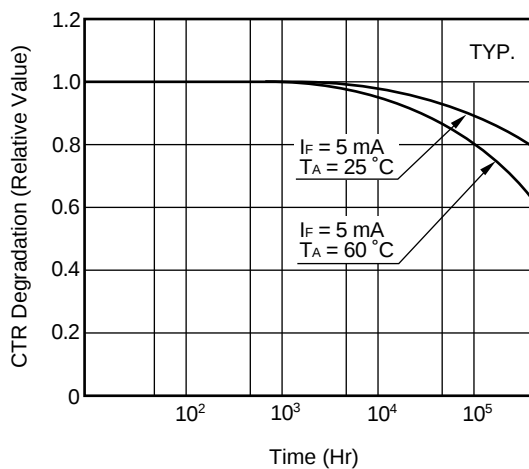
SWITCHING TIME vs. LOAD RESISTANCE



FREQUENCY RESPONSE



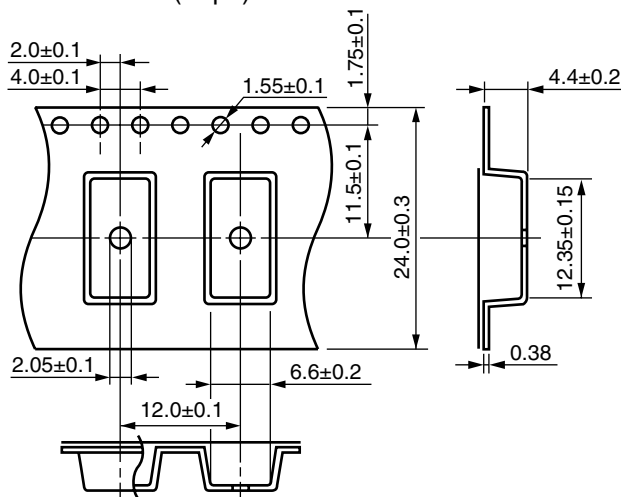
LONG TERM CTR DEGRADATION



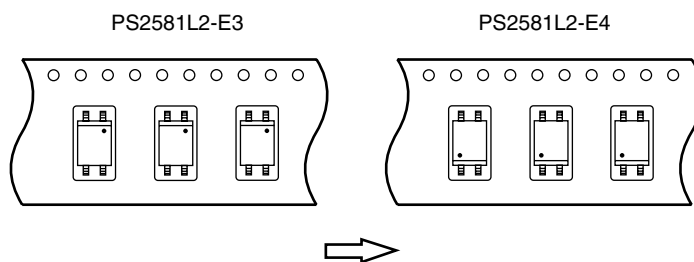
**Remark** The graphs indicate nominal characteristics.

★ TAPING SPECIFICATIONS (in millimeters)

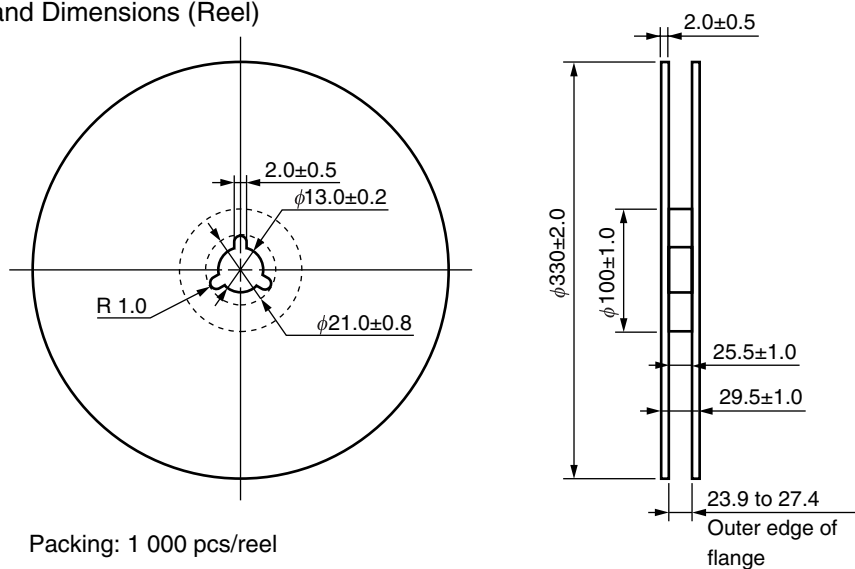
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)

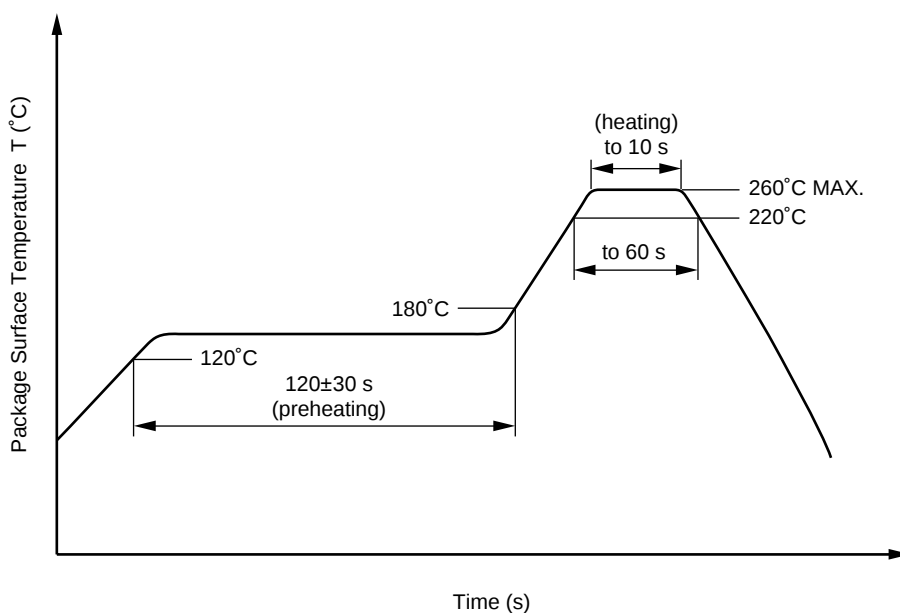


## ★ NOTES ON HANDLING

**1. Recommended soldering conditions****(1) Infrared reflow soldering**

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow

**(2) Wave soldering**

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

**(3) Cautions**

- Fluxes  
Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

**2. Cautions regarding noise**

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

★ **USAGE CAUTIONS**

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.

## SPECIFICATION OF VDE MARKS LICENSE DOCUMENT (VDE0884)

| Parameter                                                                                                                                                                                                                                                                                    | Symbol                                       | Speck                       | Unit                       |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------|-----------------------------|----------------------------|
| Application classification (DIN VDE 0109)<br>for rated line voltages $\leq 300$ Vr.m.s.<br>for rated line voltages $\leq 600$ Vr.m.s.                                                                                                                                                        |                                              | IV<br>III                   |                            |
| Climatic test class (DIN IEC 68 Teil 1/09.80)                                                                                                                                                                                                                                                |                                              | 55/100/21                   |                            |
| Dielectric strength maximum operating isolation voltage.<br>Test voltage (partial discharge test procedure a for type test and random test)<br>$U_{pr} = 1.2 \times U_{IORM}$ , $P_d < 5$ pC                                                                                                 | $U_{IORM}$<br>$U_{pr}$                       | 890<br>1 068                | $V_{peak}$<br>$V_{peak}$   |
| ★ Test voltage (partial discharge test procedure b for all devices test)<br>$U_{pr} = 1.6 \times U_{IORM}$ , $P_d < 5$ pC                                                                                                                                                                    | $U_{pr}$                                     | 1 424                       | $V_{peak}$                 |
| Highest permissible overvoltage                                                                                                                                                                                                                                                              | $U_{TR}$                                     | 8 000                       | $V_{peak}$                 |
| Degree of pollution (DIN VDE 0109)                                                                                                                                                                                                                                                           |                                              | 2                           |                            |
| Clearance distance                                                                                                                                                                                                                                                                           |                                              | $> 8.0$                     | mm                         |
| Creepage distance                                                                                                                                                                                                                                                                            |                                              | $> 8.0$                     | mm                         |
| Comparative tracking index (DIN IEC 112/VDE 0303 part 1)                                                                                                                                                                                                                                     | CTI                                          | 175                         |                            |
| Material group (DIN VDE 0109)                                                                                                                                                                                                                                                                |                                              | III a                       |                            |
| Storage temperature range                                                                                                                                                                                                                                                                    | $T_{stg}$                                    | -55 to +150                 | °C                         |
| Operating temperature range                                                                                                                                                                                                                                                                  | $T_A$                                        | -55 to +100                 | °C                         |
| Isolation resistance, minimum value<br>$V_{IO} = 500$ V dc at $T_A = 25$ °C<br>$V_{IO} = 500$ V dc at $T_A$ MAX. at least 100 °C                                                                                                                                                             | Ris MIN.<br>Ris MIN.                         | $10^{12}$<br>$10^{11}$      | $\Omega$<br>$\Omega$       |
| Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve)<br>Package temperature<br>Current (input current $I_F$ , $P_{si} = 0$ )<br>Power (output or total power dissipation)<br>Isolation resistance<br>$V_{IO} = 500$ V dc at $T_A = 175$ °C ( $T_{si}$ ) | $T_{si}$<br>$I_{si}$<br>$P_{si}$<br>Ris MIN. | 175<br>400<br>700<br>$10^9$ | °C<br>mA<br>mW<br>$\Omega$ |

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

| Restricted Substance per RoHS | Concentration Limit per RoHS (values are not yet fixed) | Concentration contained in CEL devices |     |
|-------------------------------|---------------------------------------------------------|----------------------------------------|-----|
|                               |                                                         | -A                                     | -AZ |
| Lead (Pb)                     | < 1000 PPM                                              | Not Detected                           | (*) |
| Mercury                       | < 1000 PPM                                              | Not Detected                           |     |
| Cadmium                       | < 100 PPM                                               | Not Detected                           |     |
| Hexavalent Chromium           | < 1000 PPM                                              | Not Detected                           |     |
| PBB                           | < 1000 PPM                                              | Not Detected                           |     |
| PBDE                          | < 1000 PPM                                              | Not Detected                           |     |

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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